

# 2MBI100VA-120-50

IGBT Modules

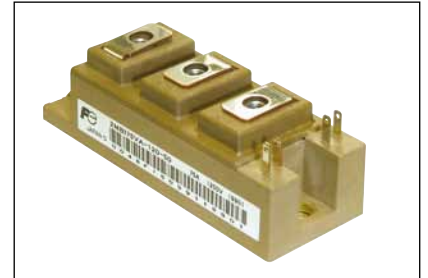
## IGBT MODULE (V series) 1200V / 100A / 2 in one package

### ■ Features

- High speed switching
- Voltage drive
- Low Inductance module structure

### ■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial machines, such as Welding machines



### ■ Maximum Ratings and Characteristics

#### ● Absolute Maximum Ratings (at T<sub>c</sub>=25°C unless otherwise specified)

Items	Symbols	Conditions	Maximum ratings	Units
Collector-Emitter voltage	V <sub>CEs</sub>		1200	V
Gate-Emitter voltage	V <sub>GES</sub>		±20	V
Collector current	I <sub>c</sub>	Continuous T <sub>c</sub> =100°C	100	A
	I <sub>c pulse</sub>	1ms	200	
	-I <sub>c</sub>		100	
	-I <sub>c pulse</sub>	1ms	200	
Collector power dissipation	P <sub>c</sub>	1 device	555	W
Junction temperature	T <sub>j</sub>		175	°C
Operating junction temperature (under switching conditions)	T <sub>jop</sub>		150	
Case temperature	T <sub>c</sub>		125	
Storage temperature	T <sub>stg</sub>		-40 ~ 125	
Isolation voltage	V <sub>iso</sub>	AC : 1min.	2500	
Screw torque	Mounting (*2)		5.0	N m
	Terminals (*3)		5.0	

Note \*1: All terminals should be connected together when isolation test will be done.

Note \*2: Recommendable Value : 3.0-5.0 Nm (M5 or M6)

Note \*3: Recommendable Value : 2.5-3.5 Nm (M5)

#### ● Electrical characteristics (at T<sub>j</sub>= 25°C unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Zero gate voltage collector current	I <sub>CEs</sub>	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 1200V	-	-	1.0	mA	
Gate-Emitter leakage current	I <sub>GES</sub>	V <sub>CE</sub> = 0V, V <sub>GE</sub> = ±20V	-	-	200	nA	
Gate-Emitter threshold voltage	V <sub>GE(th)</sub>	V <sub>CE</sub> = 20V, I <sub>c</sub> = 100mA	6.0	6.5	7.0	V	
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub> (terminal)	V <sub>GE</sub> = 15V I <sub>c</sub> = 100A	T <sub>j</sub> =25°C	-	1.90	2.35	V
			T <sub>j</sub> =125°C	-	2.20	-	
			T <sub>j</sub> =150°C	-	2.25	-	
	V <sub>CE(sat)</sub> (chip)	V <sub>GE</sub> = 15V I <sub>c</sub> = 100A	T <sub>j</sub> =25°C	-	1.75	2.20	
			T <sub>j</sub> =125°C	-	2.05	-	
			T <sub>j</sub> =150°C	-	2.10	-	
Internal gate resistance	R <sub>G(int)</sub>	-	-	7.5	-	Ω	
Input capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0V, f = 1MHz	-	9.1	-	nF	
Turn-on time	t <sub>on</sub>	V <sub>CC</sub> = 600V L <sub>s</sub> = 30nH	-	600	-	nsec	
	t <sub>r</sub>	I <sub>c</sub> = 100A	-	200	-		
	t <sub>r(0)</sub>	V <sub>GE</sub> = ±15V	-	50	-		
Turn-off time	t <sub>off</sub>	R <sub>G</sub> = 1.6Ω	-	600	-	nsec	
	t <sub>r</sub>	T <sub>j</sub> = 150°C	-	40	-		
Forward on voltage	V <sub>F</sub> (terminal)	V <sub>GE</sub> = 0V I <sub>F</sub> = 100A	T <sub>j</sub> =25°C	-	1.80	2.25	V
			T <sub>j</sub> =125°C	-	1.95	-	
			T <sub>j</sub> =150°C	-	1.90	-	
	V <sub>F</sub> (chip)	V <sub>GE</sub> = 0V I <sub>F</sub> = 100A	T <sub>j</sub> =25°C	-	1.70	2.15	
			T <sub>j</sub> =125°C	-	1.85	-	
			T <sub>j</sub> =150°C	-	1.80	-	
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = 100A	-	150	-	nsec	

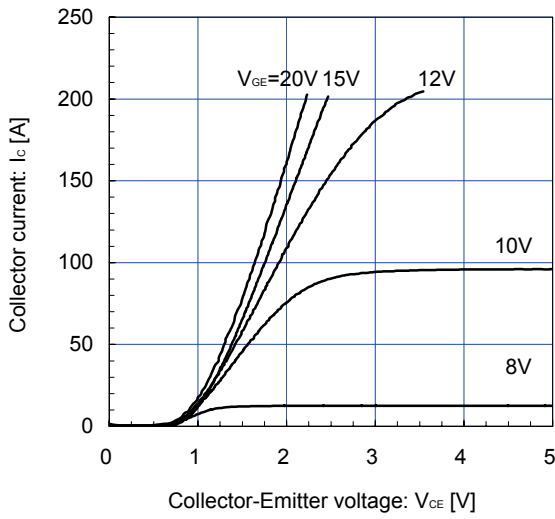
#### ● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	R <sub>th(j-c)</sub>	IGBT	-	-	0.27	°C/W
		FWD	-	-	0.48	
Contact thermal resistance (1device) (*4)	R <sub>th(c-f)</sub>	with Thermal Compound	-	0.050	-	

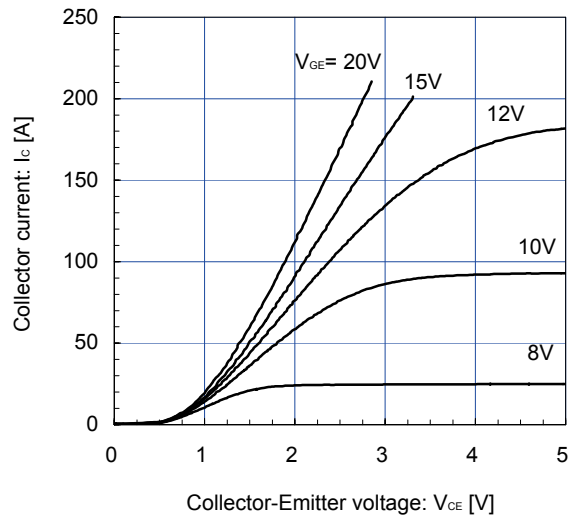
Note \*4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

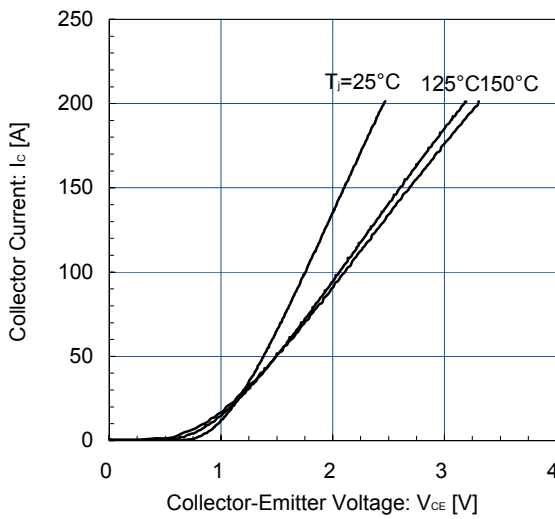
Collector current vs. Collector-Emittter voltage (typ.)  
 $T_j = 25^\circ\text{C}$  / chip



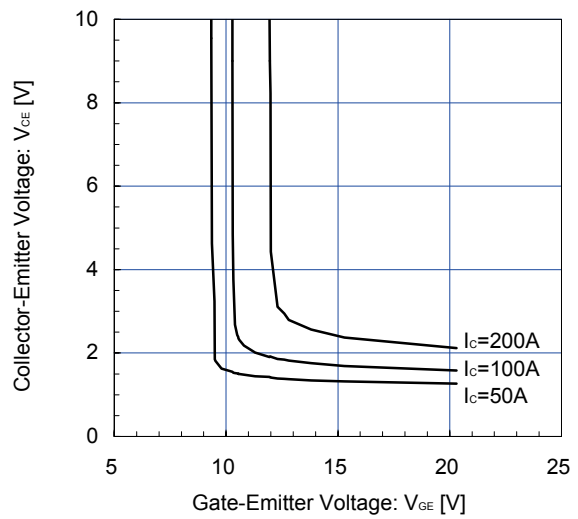
Collector current vs. Collector-Emittter voltage (typ.)  
 $T_j = 150^\circ\text{C}$  / chip



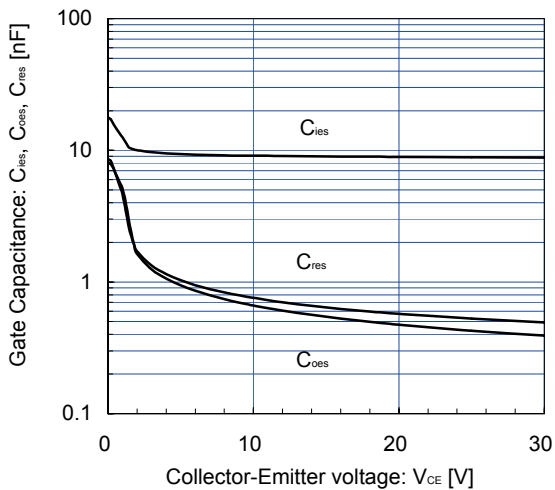
Collector current vs. Collector-Emittter voltage (typ.)  
 $V_{GE} = 15\text{V}$  / chip



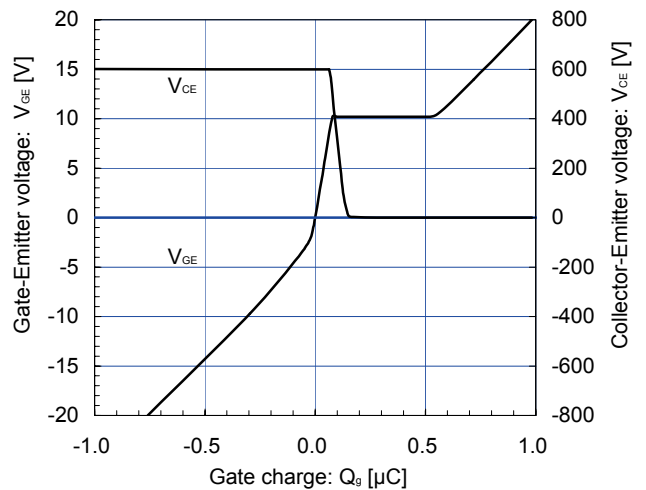
Collector-Emittter voltage vs. Gate-Emittter voltage  
 $T_j = 25^\circ\text{C}$  / chip



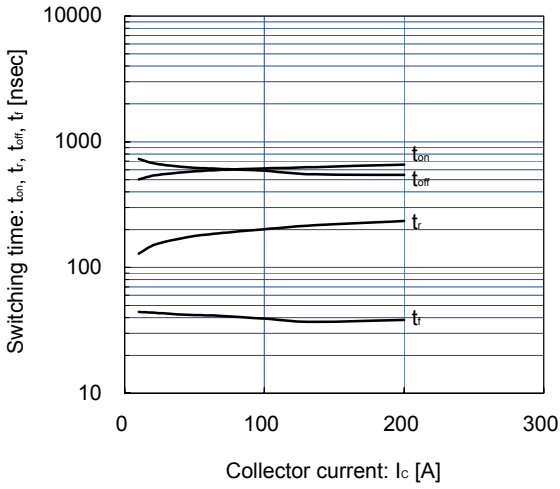
Gate Capacitance vs. Collector-Emittter Voltage  
 $V_{GE} = 0\text{V}$ ,  $f = 1\text{MHz}$ ,  $T_j = 25^\circ\text{C}$



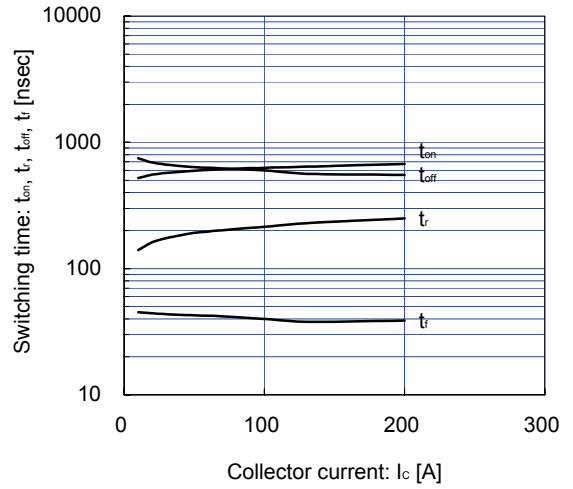
Dynamic Gate Charge (typ.)  
 $V_{CC} = 600\text{V}$ ,  $I_C = 100\text{A}$ ,  $T_j = 25^\circ\text{C}$



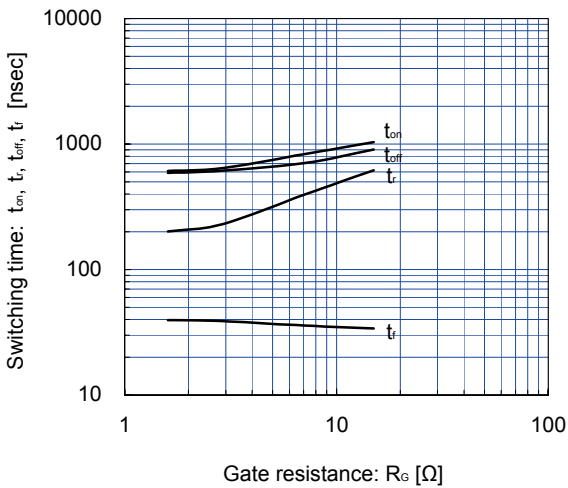
Switching time vs. Collector current (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=1.6\Omega, T_J=125^\circ C$



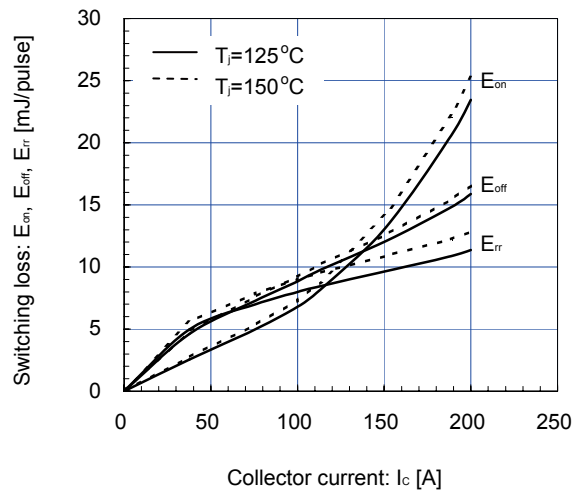
Switching time vs. Collector current (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=1.6\Omega, T_J=150^\circ C$



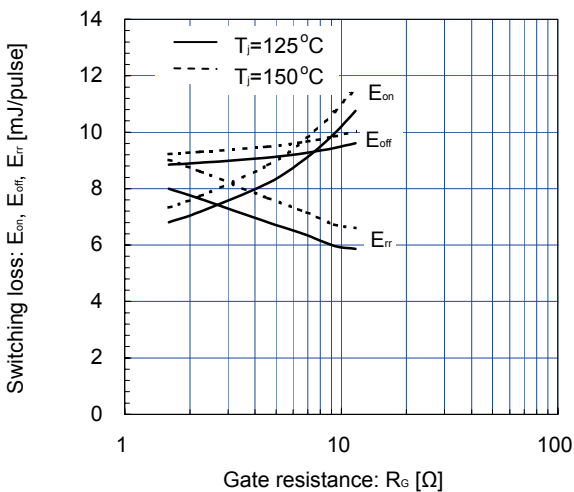
Switching time vs. Gate resistance (typ.)  
 $V_{CC}=600V, I_C=100A, V_{GE}=\pm 15V, T_J=125^\circ C$



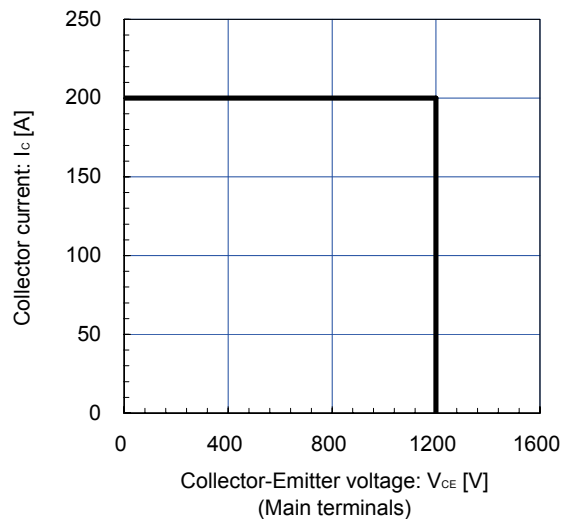
Switching loss vs. Collector current (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=1.6\Omega, T_J=125, 150^\circ C$



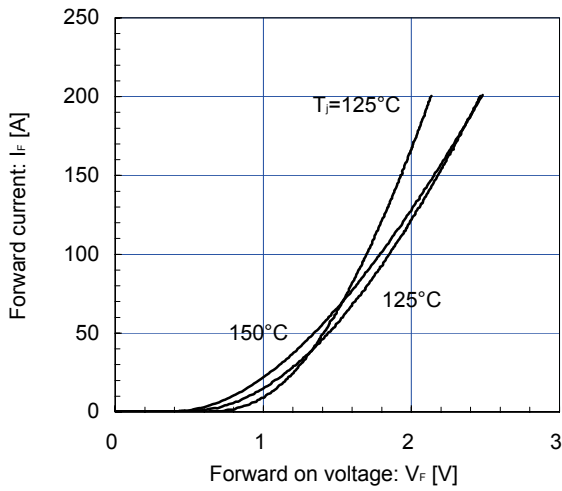
Switching loss vs. Gate resistance (typ.)  
 $V_{CC}=600V, I_C=100A, V_{GE}=\pm 15V, T_J=125, 150^\circ C$



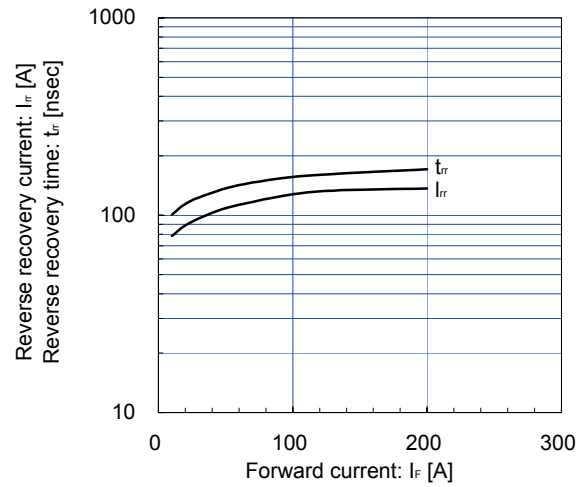
Reverse bias safe operating area (max.)  
 $+V_{GE}=15V, -V_{GE}=15V, R_G=1.6\Omega, T_J=150^\circ C$



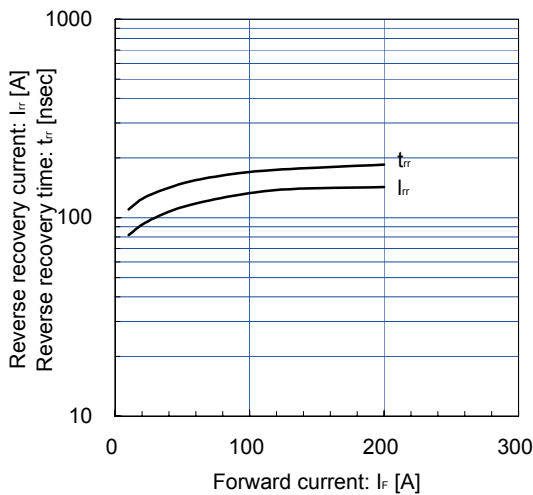
Forward Current vs. Forward Voltage (typ.)  
chip



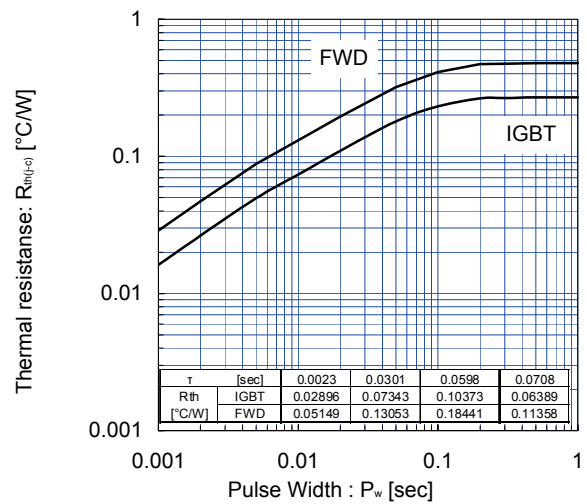
Reverse Recovery Characteristics (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=1.6\Omega, T_J=125^\circ C$



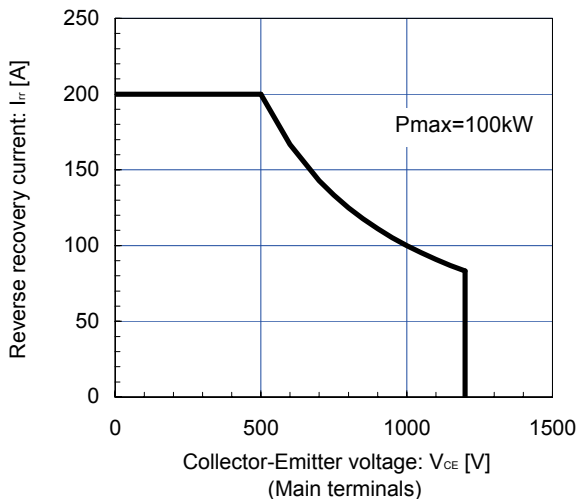
Reverse Recovery Characteristics (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=1.6\Omega, T_J=150^\circ C$



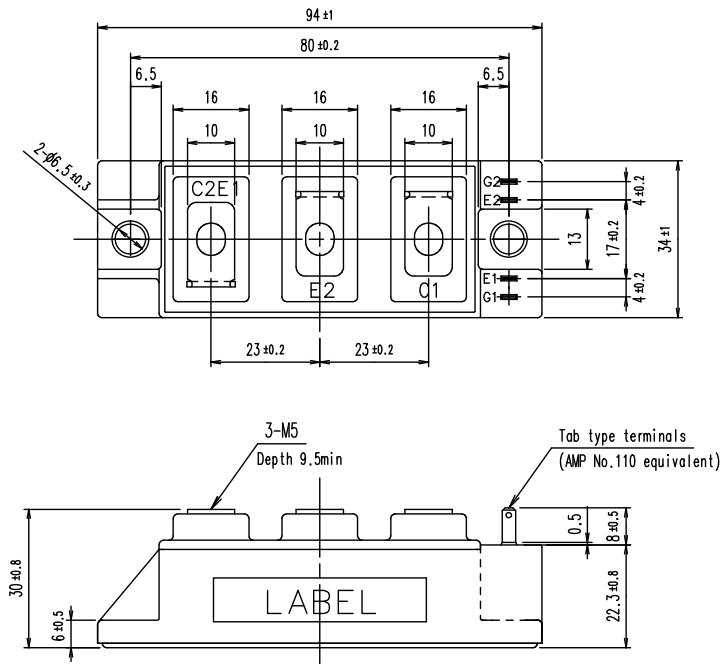
Transient Thermal Resistance (max.)



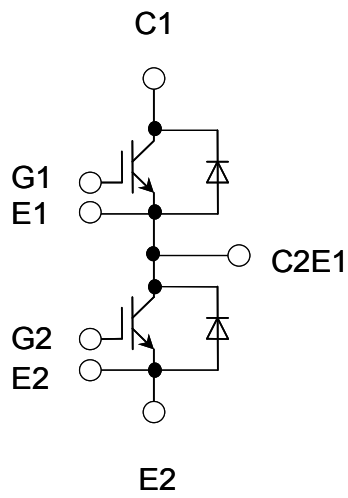
FWD safe operating area (max.)  
 $T_J=150^\circ C$



■ Outline Drawings, mm



■ Equivalent Circuit Schematic



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